

In th Specification

Please amend the title as follows:

~~Transistor Devices, CMOS Constructions, Capacitor Constructions, and Methods of~~
Forming Transistor Devices and Capacitor Constructions

At page 1, before the "Technical Field" section, please insert,

RELATED PATENT DATA

This patent resulted from a divisional application of U.S. Patent Application Serial
No. 10/388,103, which was filed March 12, 2003.